



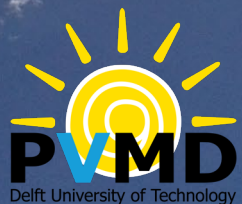
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# Understanding the electron transport mechanisms in $\text{MoO}_x$ -based layer stack for application in simplified IBC-SHJ solar cells

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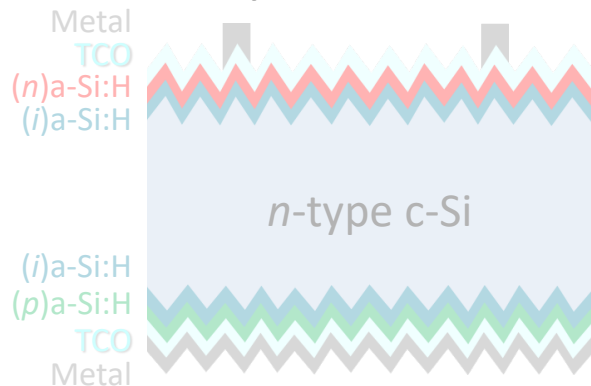
4<sup>th</sup> of December 2024  
Delft, The Netherlands  
BCworkshop 2024



# Silicon heterojunction (SHJ) solar cells

## Front/back-contacted (FBC)

$$\eta = 26.81\% [1]$$

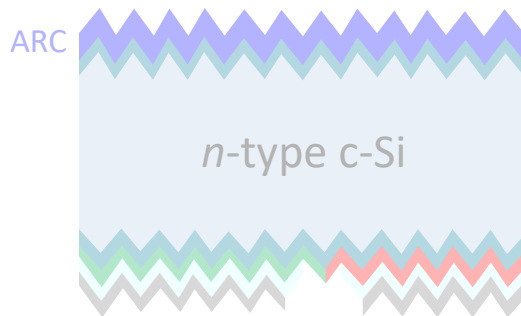


$$V_{OC} > 750 \text{ mV} [1]$$

Limited potential for  $J_{SC}$

## Interdigitated-back-contacted (IBC)

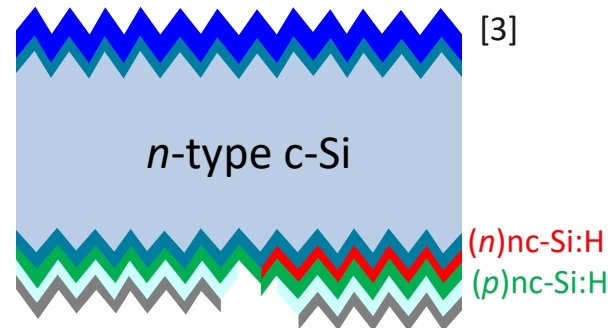
$$\eta = 27.3\% [2]$$



Optimized front side

Complex fabrication

$$\eta = 25.4\% [4]$$



Reduced complexity

Challenge to control high shunt resistance<sup>[4]</sup>

## Simple processing and controlable high shunt resistance?

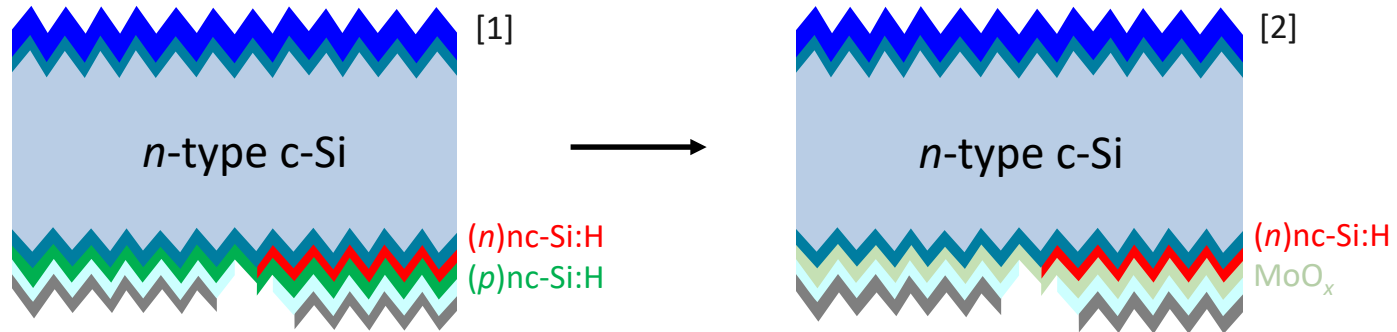
[1] H. Lin, et al., *Nat. Energy*, **8**, 789 (2023)

[2] H. Wu, et al., *Nature*, **635**, 604 (2024)

[3] A. Tomasi, et al., *Nat. Energy*, **2**, 17062 (2017)

[4] D. Lachenal, *bifiPV Workshop*, Zhuhai, China (2024)

# Alternative material choice



- ➡ Low lateral conductivity of MoO<sub>x</sub> [3]
- ➡  $\eta = 23.83\%$  FBC-SHJ solar cell with  $\sim 2$  nm MoO<sub>x</sub> as HTL [4]
- ➡ Potentially faster processing of blanket layer
- ➡ Novel ETL with ( $n$ )nc-Si:H and MoO<sub>x</sub> [2, 5]

[1] A. Tomasi, et al., *Nat. Energy*, **2**, 17062 (2017)

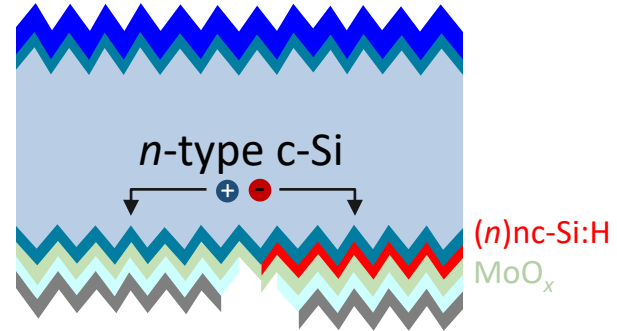
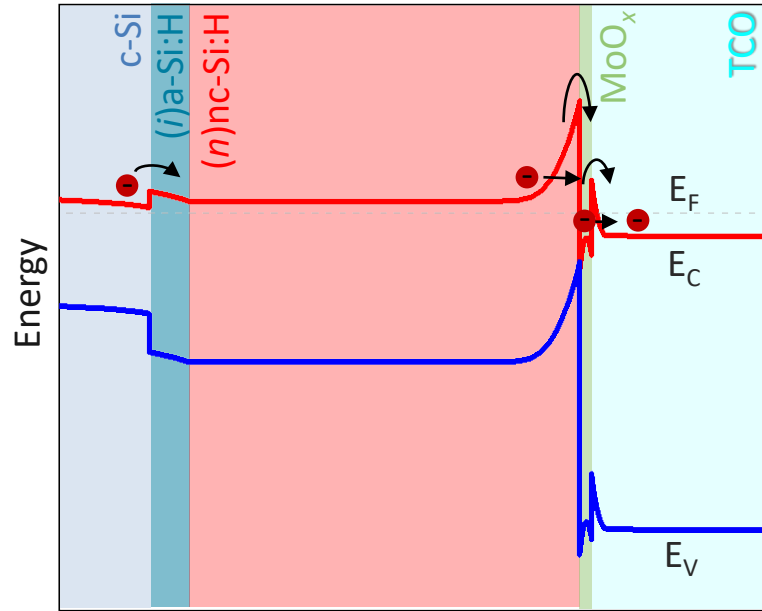
[2] K. Kovačević, et al., *Prog. Photovolt. Res. Appl.*, (2024)

[3] L. Gerling, et al., *Sol. Energ. Mater. Sol. Cells*, **145**, 109 (2016)

[4] L. Cao, et al., *Prog. Photovolt. Res. Appl.*, **31**, 1245 (2022)

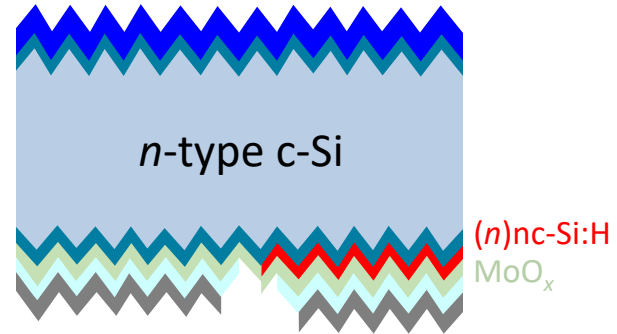
[5] K. Kovačević, et al., *To be submitted*

# Working principle of the electron transport layer (ETL) stack



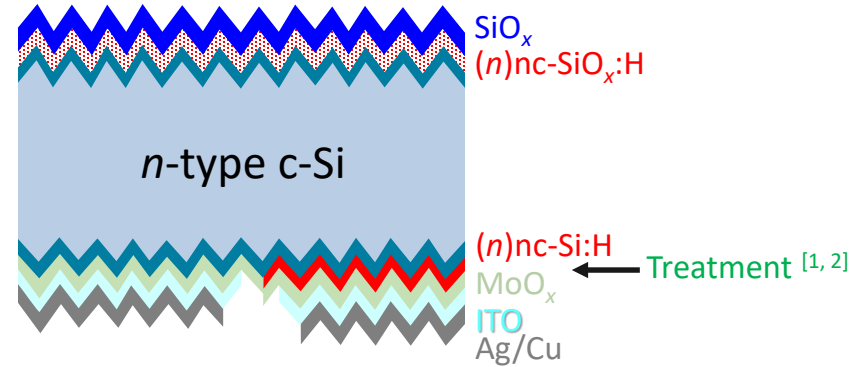
➡ Charge transfer in conduction band and no recombination junction

# IBC-SHJ solar cells with MoO<sub>x</sub> blanket layer



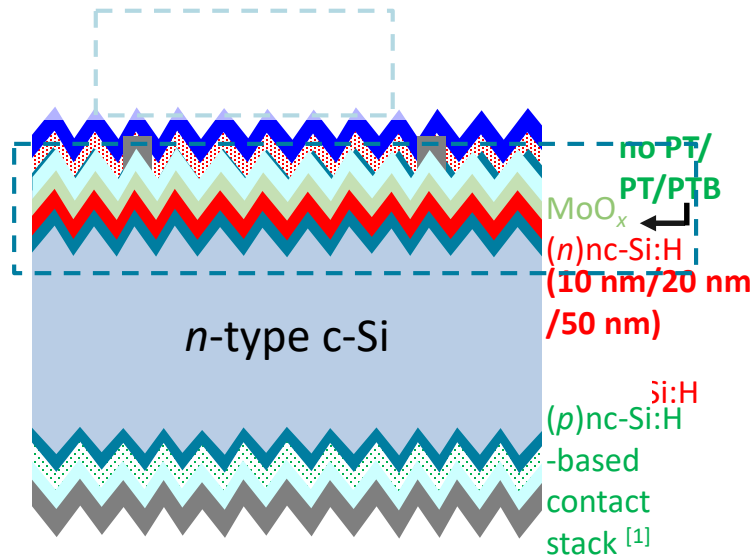
# IBC-SHJ solar cells with MoO<sub>x</sub> blanket layer

- Optimization of electron transport layer (ETL) stack
- Understanding of charge carrier collection
  - Effect of temperature
  - Interface analysis



$\eta > 23\%$

# ETL contact stack evaluation



## Experimental evaluation of passivation and transport

➔ Plasma treatment (PT)  
 $\text{SiH}_4, \text{H}_2, \text{CO}_2$  [2]

and plasma treatment with boron (PTB)  
 $\text{SiH}_4, \text{H}_2, \text{CO}_2, \text{B}_2\text{H}_6$  [2, 3]

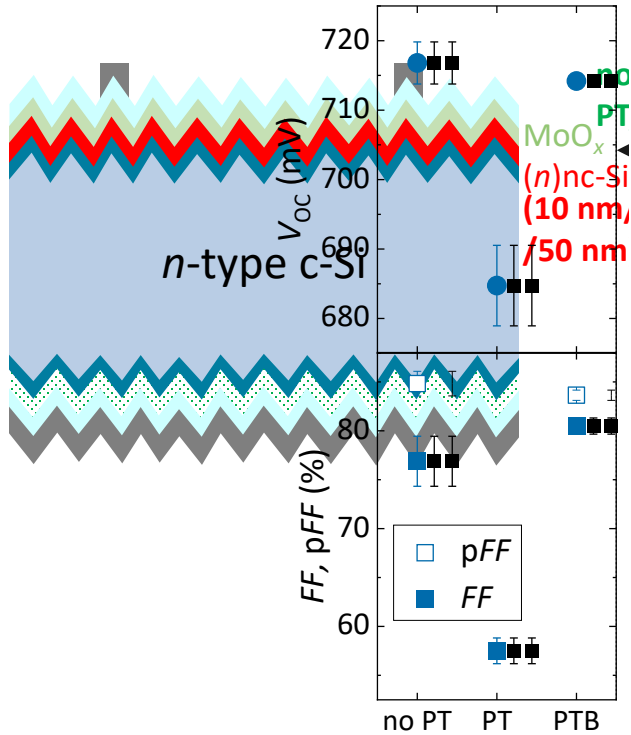
➔  $(n)\text{nc-Si:H}$  thickness

[1] Y. Zhao, et al., *Sol. Energ. Mater. Sol. Cells*, **219**, 110779 (2021)

[2] L. Cao, et al., *Prog. Photovolt. Res. Appl.*, **31**, 1245 (2022)

[3] L. Mazzarella, et al., *Prog. Photovolt. Res. Appl.*, **29**, 391 (2020)

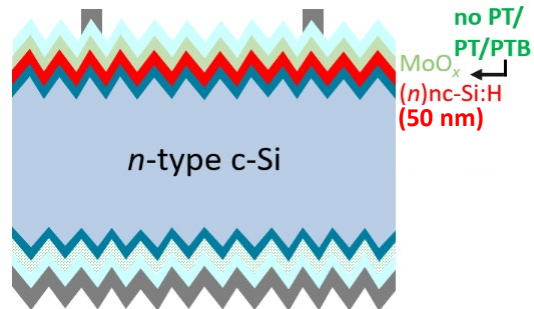
# ETL contact stack evaluation



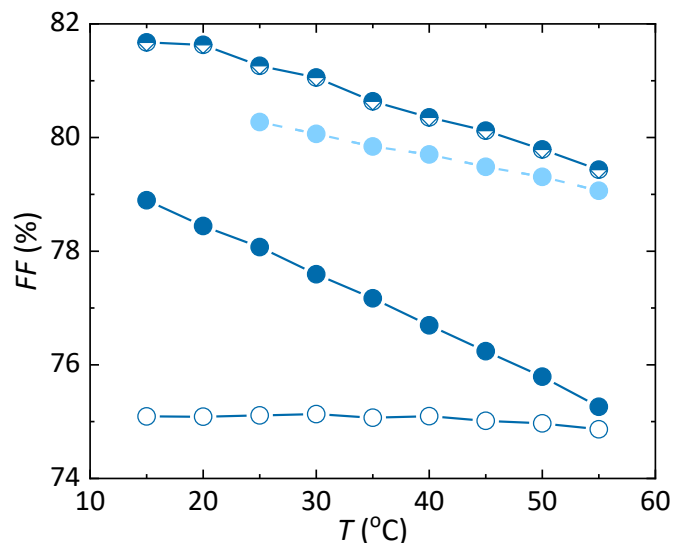
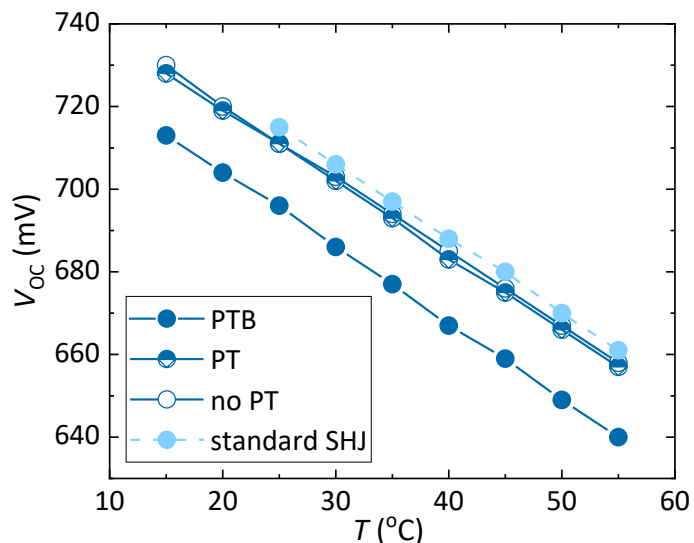
- ➔ Comparable  $V_{oc}$  and pFF
- ➔ Improved FF from (n)nc-Si:H/MoO<sub>x</sub>
- ➔ Overall improvement with PTB and lower sensitivity to (n)nc-Si:H thickness



# Effect of temperature



Temperature  $\uparrow$   $\rightarrow$  Recombination  $\uparrow$   $\rightarrow$   $V_{OC}$   $\downarrow$  &  $FF$   $\downarrow$  [1, 2]



$\rightarrow$  Transport based on direct energy transitions

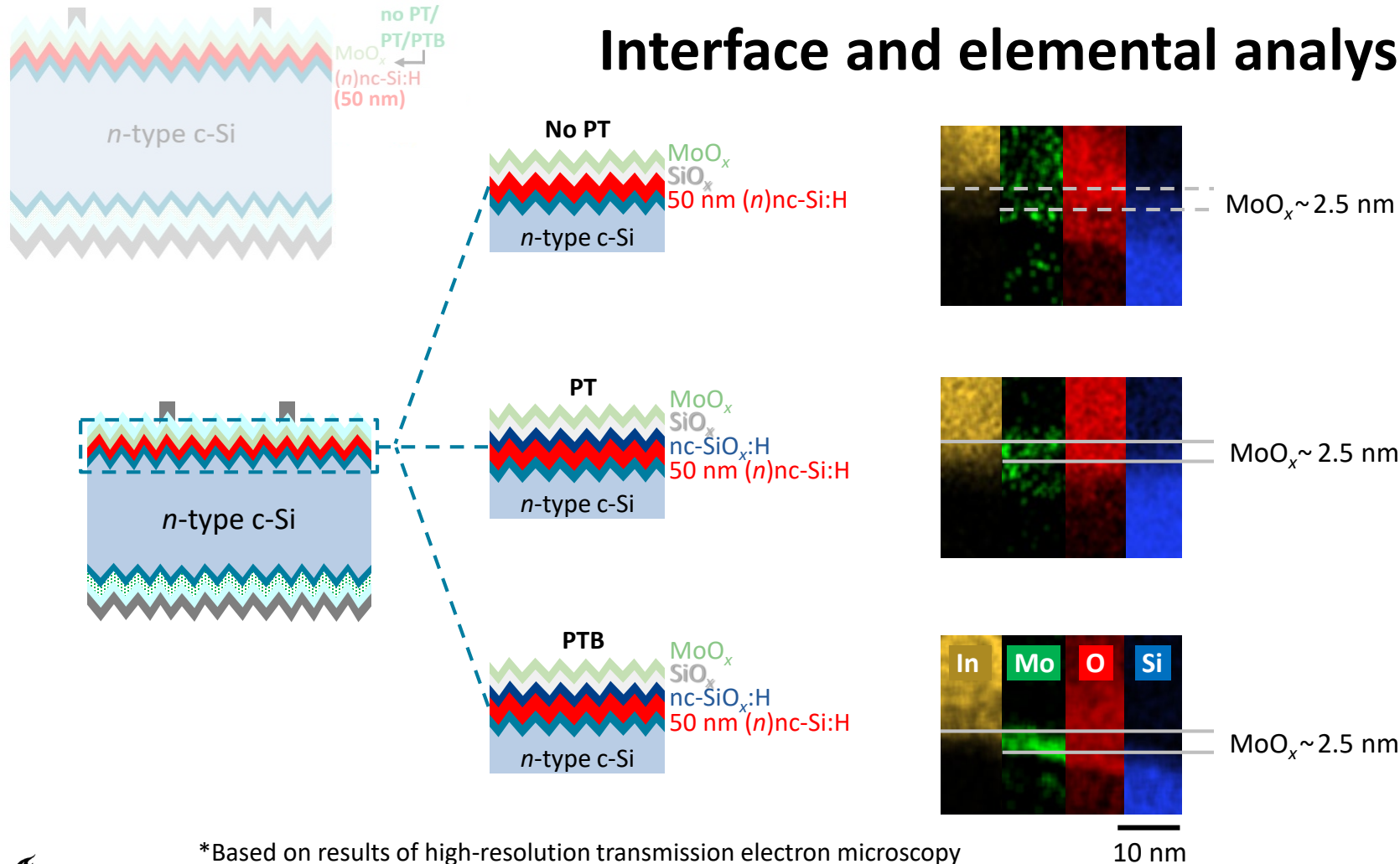
enabled by PT and PTB [3]

[1] R. N. Hall, *Phys Rev*, **87**, 387 (1952)

[2] W. Shockley and W. T. Read, *Phys Rev*, **87**, 835 (1952)

[3] L. Mazzarella, et al., *Prog. in Photovolt. Res. Appl*, **29**, 391 (2020)

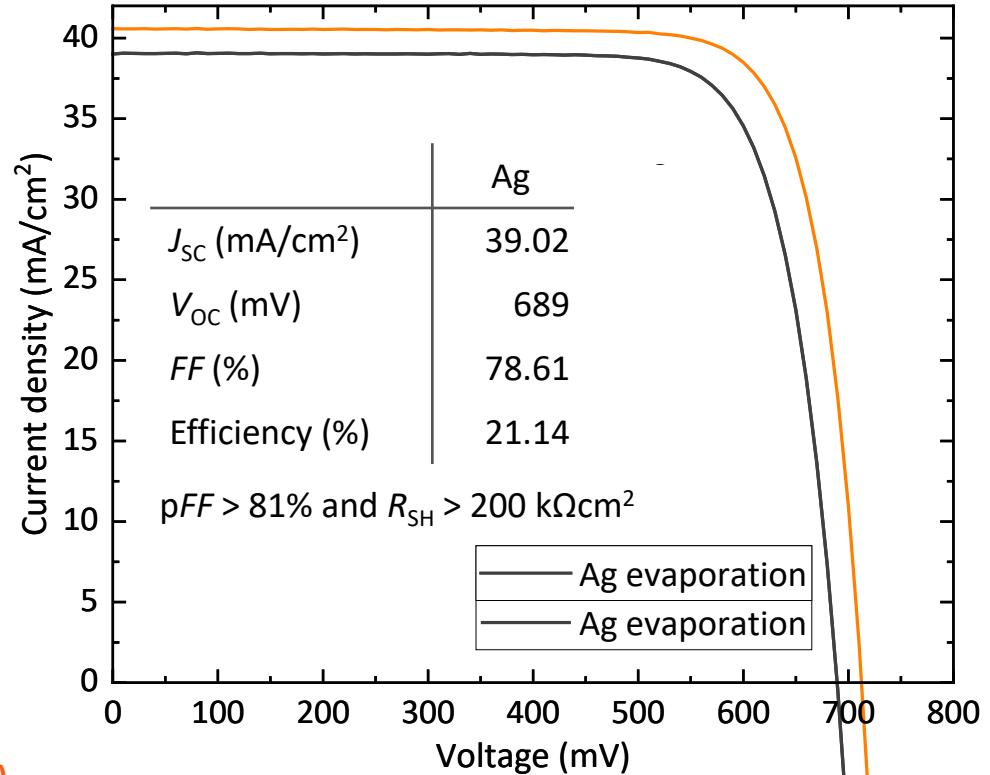
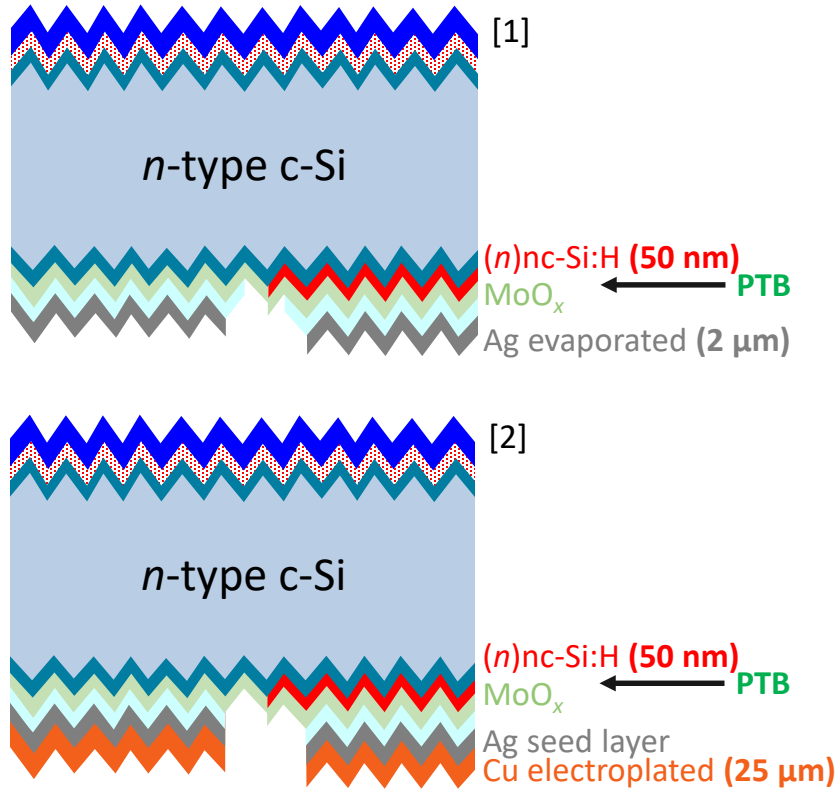
# Interface and elemental analysis\*



\*Based on results of high-resolution transmission electron microscopy

10 (HR-TEM) and energy-dispersive X-ray spectroscopy (EDX) analysis

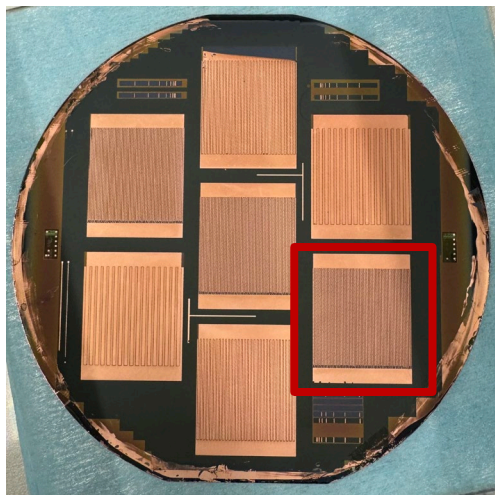
# IBC-SHJ solar cells with MoO<sub>x</sub> blanket layer



[1] K. Kovačević, et al., *Prog. Photovolt. Res. Appl.*, (2024)

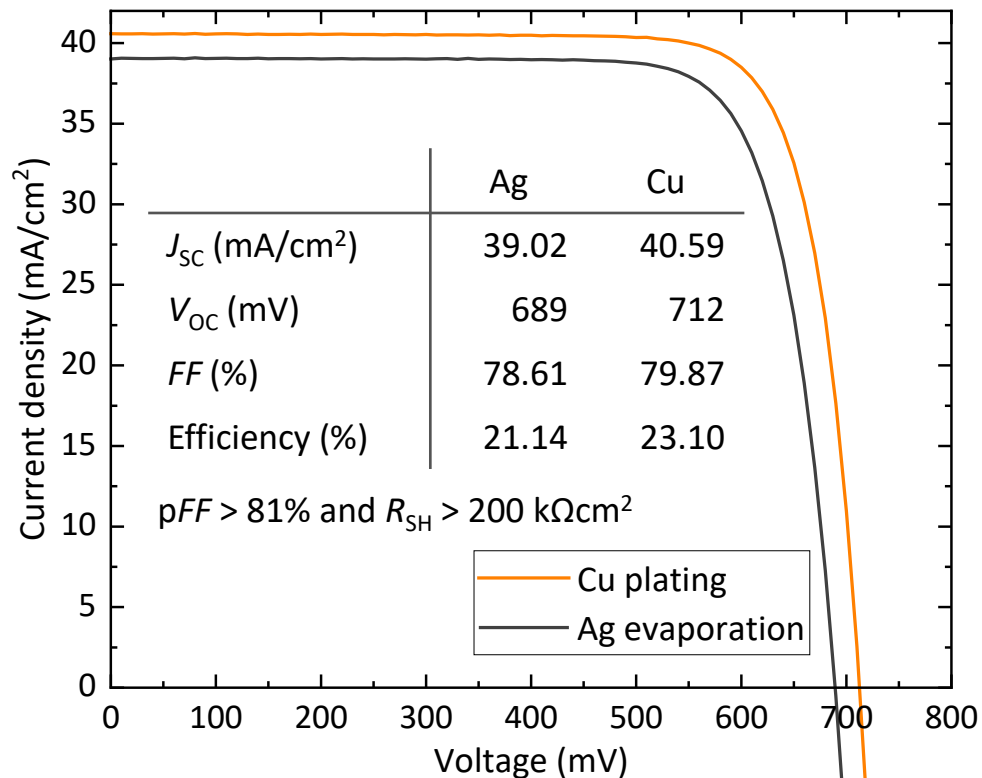
[2] K. Kovačević, et al., *To be submitted*

# IBC-SHJ solar cells with MoO<sub>x</sub> blanket layer



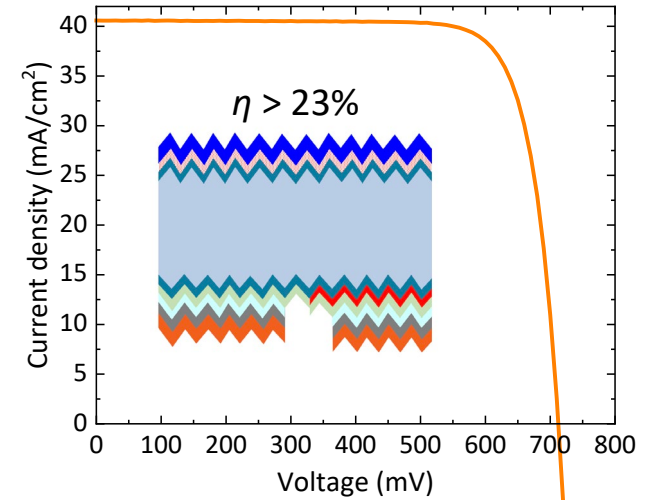
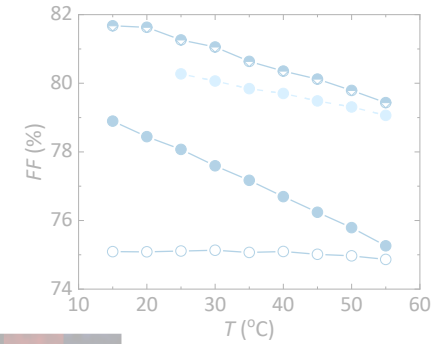
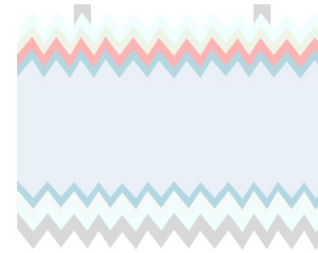
Future optimization towards  $\eta > 24\%$

- Passivation enhancement
- (*n*)nc-Si:H improvement
- Double layer anti-reflection coating
- Metal grid redesign for higher bifaciality



# Conclusion

- Optimization of electron transport layer (ETL) stack
- Understanding of charge carrier collection
  - Effect of temperature
  - Interface analysis



# Thank you for your attention!

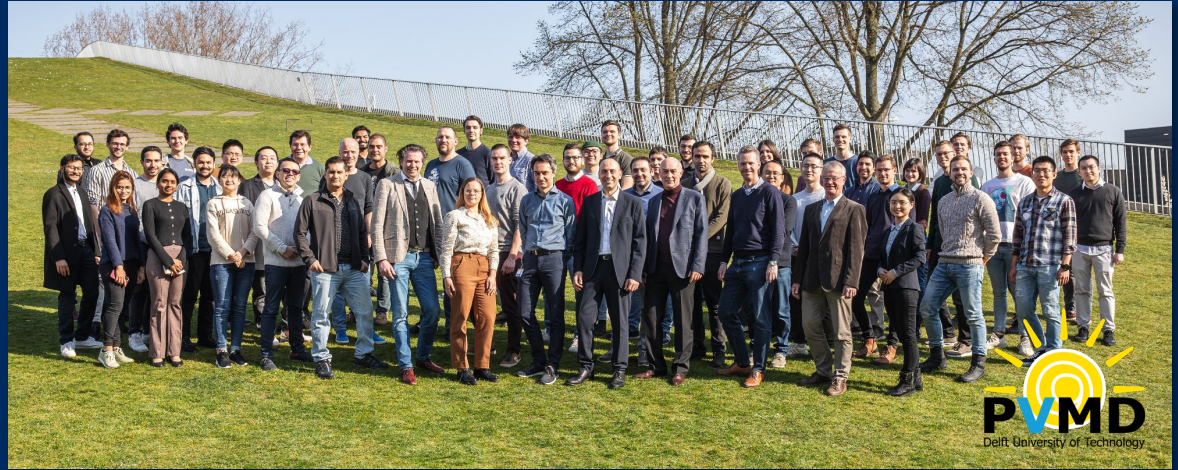
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# IBC-SHJ solar cells with MoO<sub>x</sub> blanket layer

